

Wednesday, August 31, 2016

Section XVIII	
Interface states	
9:00 – 12:05	Chair: G. Logvenov
9:00 – 10:20	Interfacial effects and superconductivity in oxide heterostructures <i>J.-M. Triscone, University of Geneva, Switzerland</i>
10:20 – 10:40	Coffee
10:40 – 11:10	Novel two-dimensional electron systems at oxide interfaces: nanoscale and ultrafast control <i>A. Caviglia, Delft University of Technology, The Netherlands</i>
11:10 – 11:40	Melting of electronic crystals in organic transistor interface <i>H.M. Yamamoto, IMS, Japan</i>
11:40 – 12:05	Magnetofermionic condensate in two dimensions <i>L. Kulik, Institute of Solid State Physics, Russia</i>
12:15 – 14:30	Lunch
Section XIX	
PIPT theory	
14:30 – 15:30	Chair: M. Fabrizio
14:30 – 14:55	Carrier relaxation and multiplication in photo-doped Mott insulators <i>Ph. Werner, University of Fribourg, Switzerland</i>
14:55 – 15:30	Optical and electric-field impacts in strongly charge correlated systems <i>S. Ishihara, Tohoku University, Japan</i>
15:30 – 16:00	Coffee
17:00	Social activity: Bus excursion